

Amplifier for infrared detector

C4159/C5185 series, C3757-02

Low noise amplifier for InGaAs, PbS, PbSe and MCT detector



Accessories

- Instruction manual
- 4-conductor cable (with a connector; 2 m) A4372-02

■ Absolute maximum ratings (Ta=25 °C)

Parameter	Value	Unit
Operating temperature	0 to +40	°C
Storage temperature	-20 to +70	°C

■ Amplifiers for photovoltaic detectors (Typ.)

Parameter	C4159-01	C4159-04	C4159-02	C4159-03	Unit
Applicable detector	InSb *2 ($\phi 0.6$ mm, 1 mm)	InSb *2 ($\phi 2$ mm)	InGaAs	InGaAs	-
Conversion impedance	$10^8, 10^7, 10^6$ (3 ranges switchable)	$2 \times 10^7, 2 \times 10^6, 2 \times 10^5$ (3 ranges switchable)	250 to 5×10^3 continuous	$10^7, 10^6, 10^5$ (3 ranges switchable)	V/A
Frequency response (amp. only, -3 dB)	DC to 100 k	DC to 45 k	20 to 120 M	DC to 15 k	Hz
Output impedance	50	50	50	50	Ω
Maximum output voltage (1 k Ω load)	+10	+10	± 1.3	+10	V
Output offset voltage	± 5	± 5	± 30	± 5	mV
Equivalent input noise current (f=1 kHz)	0.15 *1	0.55	30	2.5	pA/Hz ^{1/2}
Reverse voltage	Impossible		Internally generated	Can be applied from external unit	-
External power supply	± 15		± 15	± 15	V
Current consumption	+30, -10 Max.		+90, -60 Max.	± 15 Max.	mA

*1: 0.65 pA/Hz^{1/2} when conversion impedance is set to 10^6 V/A.

*2: Amplifiers for multi-element detectors are separately provided.

Note) Output noise voltage = Equivalent input noise current $\times$ Conversion impedance

■ Amplifiers for photoconductive detectors (Typ.)

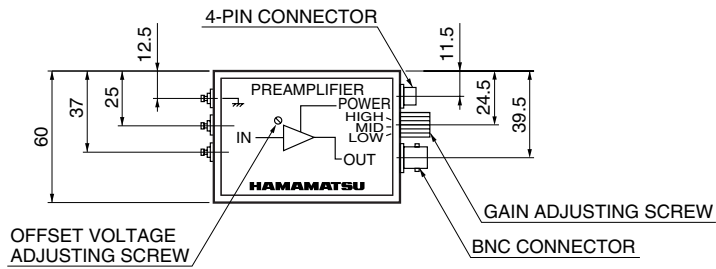
Parameter	C5185	C5185-01	C3757-02	Unit
Applicable detector	MCT (dewar type)	MCT (TE-cooled)	PbS, PbSe	-
Input impedance	5	5	10000	k Ω
Voltage gain	66 ($\times 2000$)	66 ($\times 2000$)	40 ($\times 100$)	dB
Frequency response (amp. only, -3 dB)	5 to 250 k	5 to 250 k	0.2 to 10 k	Hz
Detector bias current	5 mA, 10 mA, 15 mA (3 ranges switchable)	0.1 mA, 0.5 mA, 1 mA (3 ranges switchable)	Internal bias	-
Output impedance	50	50	50	Ω
Maximum output voltage (1 k Ω load)	± 2.5	± 2.5	± 10	V
Equivalent input noise voltage (f=1 kHz)	2.6	1.2	40	nV/Hz ^{1/2}
External power supply	± 15	± 15	± 15	V
Current consumption	+60, -10 Max.	+60, -10 Max.	+15, -15 Max.	mA

Note) Output noise voltage = Equivalent input noise voltage $\times$ Voltage gain

Amplifier for infrared detector C4159/C5185 series, C3757-02

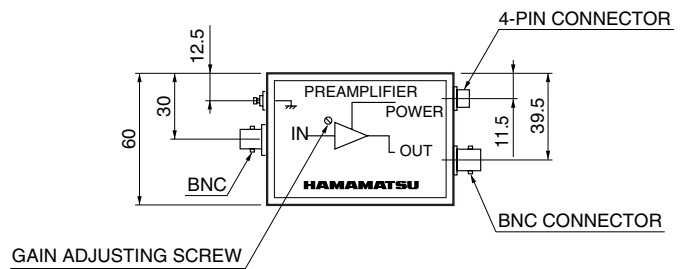
■ Dimensional outlines (unit: mm)

C4159-01/-03/-04



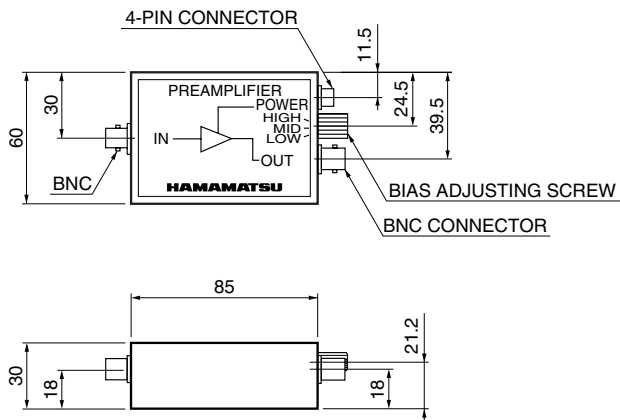
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C4159-02



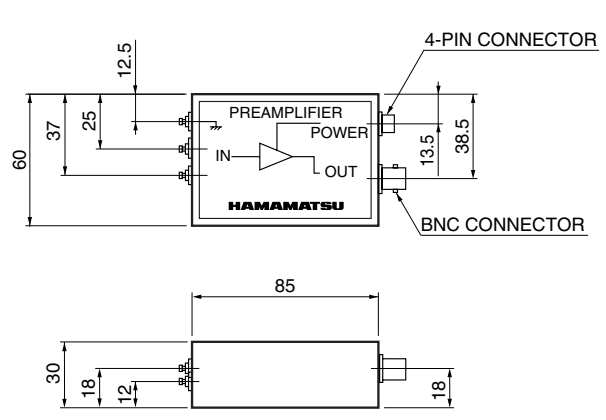
KIRDA0047EA

C5185-01



KIRDA0048EB

C3757-02



KIRDA0049EA

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HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Hamamatsu City, 435-8558 Japan, Telephone: (81) 053-434-3311, Fax: (81) 053-434-5184, <http://www.hamamatsu.com>

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, P.O.Box 6910, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218

Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 08152-3750, Fax: (49) 08152-2658

France: Hamamatsu Photonics France S.A.R.L.: 8, Rue du Saule Trappu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10

United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777

North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171 41 Solna, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01

Italy: Hamamatsu Photonics Italia S.R.L.: Strada della Moia, 1/E, 20020 Arese, (Milano), Italy, Telephone: (39) 02-935-81-733, Fax: (39) 02-935-81-741